

5-V PECL-to-TTL Translator

FEATURES

- 3ns (TYP) Propagation Delay
- Operating Range: $V_{CC} = 4.2\text{ V}$ to 5.7 V with $GND = 0\text{ V}$
- 24-mA TTL Output
- Deterministic Output Value for Open Input Conditions or When Inputs $< 1.3\text{ V}$
- Built-In Temperature Compensation
- Drop-In Compatible to the MC10ELT21, MC100ELT21

APPLICATIONS

- Data and Clock Transmission Over Backplane
- Signaling Level Conversion for Clock or Data

DESCRIPTION

The SN65ELT21 is a differential PECL-to-TTL translator. It operates on +5-V supply and ground only. The device includes circuitry to maintain Q to a low logic level when inputs are in an open condition or $< 1.3\text{ V}$.

The V_{BB} pin is a reference voltage output for the device. When the device is used in single-ended mode, the unused input should be tied to V_{BB} . This reference voltage can also be used to bias the input when it is ac coupled. When it is used, place a $0.01\mu\text{F}$ decoupling capacitor between V_{CC} and V_{BB} . Also limit the sink/source current to $< 0.5\text{ mA}$ to V_{BB} . Leave V_{BB} open when it is not used.

The SN65ELT21 is housed in an industry standard SOIC-8 package and is also available in an optional TSSOP-8 package.

PIN ASSIGNMENT

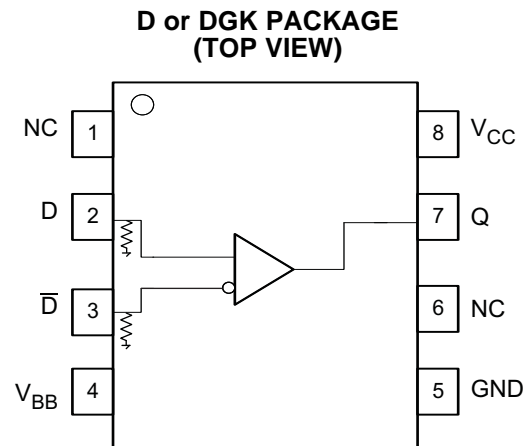


Table 1. Pin Descriptions

PIN	FUNCTION
D, \bar{D}	PECL data inputs
Q	TTL output
V_{CC}	Positive supply
V_{EE}	Negative supply
V_{BB}	Reference voltage output

ORDERING INFORMATION⁽¹⁾⁽²⁾

PART NUMBER	PART MARKING	PACKAGE	LEAD FINISH
SN65ELT21D	ELT21	SOIC	NiPdAu
SN65ELT21DGK	SIII	SOIC-TSSOP	NiPdAu

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Leaded device options are not initially available; contact a sales representative for further details.



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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

PARAMETER	CONDITIONS	VALUE	UNIT
Absolute PECL mode supply voltage	V_{CC} (GND = 0 V)	6	V
Sink/source current, V_{BB}		± 0.5	mA
PECL input voltage	GND = 0 V, $V_I \leq V_{CC}$	6	V
Operating temperature range		–40 to 85	°C
Storage temperature range		–65 to 150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATINGS

PACKAGE	CIRCUIT BOARD MODEL	POWER RATING $T_A < 25^\circ\text{C}$ (mW)	THERMAL RESISTANCE, JUNCTION-TO-AMBIENT NO AIRFLOW	DERATING FACTOR $T_A > 25^\circ\text{C}$ (mW/°C)	POWER RATING $T_A = 85^\circ\text{C}$ (mW)
SOIC	Low-K	719	139	7	288
	High-K	840	119	8	336
SOIC-TSSOP	Low-K	469	213	5	188
	High-K	527	189	5	211

THERMAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNIT
θ_{JB}	Junction-to-board thermal resistance	SOIC	79		°C/W
		SOIC-TSSOP	120		
θ_{JC}	Junction-to-case thermal resistance	SOIC	98		°C/W
		SOIC-TSSOP	74		

KEY ATTRIBUTES

CHARACTERISTICS	VALUE	
Internal input pull-down resistor	50 k Ω	
Moisture sensitivity level	Level 1	
Flame ability rating (oxygen index: 28 to 34)	UL 94 V-0 at 0.125 in	
Electrostatic discharge	Human body model	2 kV
	Charged-device model	1.5 kV
Meets or exceeds JEDEC Spec EIA/JESD78 latchup test		

PECL DC CHARACTERISTICS

At $V_{CC} = 5.0\text{ V}$, $GND = 0.0\text{ V}$ (unless otherwise noted)⁽¹⁾⁽²⁾

PARAMETER	TEST CONDITIONS	$T_A = -40^\circ\text{C}$			$T_A = 25^\circ\text{C}$			$T_A = 85^\circ\text{C}$			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
V_{IH}	High-level input voltage, single-ended	3835	4120		3835	4120		3835	4120		mV
V_{IL}	Low-level input voltage, single-ended	3190	3525		3190	3525		3190	3525		mV
V_{BB}	Output reference voltage	3.62	3.69	3.74	3.62	3.69	3.74	3.62	3.69	3.74	V
V_{IHCMR}	High-level input voltage, common-mode range, differential	See ⁽³⁾			2.2	5.0		2.2	5.0		V
I_{IH}	High-level input current			150			150			150	μA
I_{IL}	Low-level input current	0.5			0.5			0.5			μA

- (1) The device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) Input parameters vary 1:1 with V_{CC} . V_{CC} can vary $+0.7\text{ V} / -0.8\text{ V}$.
- (3) $V_{IHCMR(\text{min})}$ varies 1:1 with GND , $V_{IHCMR(\text{max})}$ varies 1:1 with V_{CC} .

TTL DC CHARACTERISTICS

At $V_{CC} = 4.2\text{ V}$ to 5.7 V , $T_A = -40^\circ\text{C}$ to 85°C (unless otherwise noted)⁽¹⁾

PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{CCH}	Power supply current			20	mA
I_{CCL}	Power supply current			20	mA
V_{OH}	High-level output voltage	$I_{OH} = -3.0\text{ mA}$		2.4	See ⁽²⁾ V
V_{OL}	Low-level output voltage	$I_{OL} = 24\text{ mA}$		0.5	V
I_{OS}	Output short circuit current	-150		-60	mA

- (1) The device will meet the specifications after thermal balance has been established when mounted in a socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) $V_{OH(\text{max})}$ level is $V_{CC} - 0.7$.

AC CHARACTERISTICS

At $V_{CC} = 4.2\text{ V}$ to 5.7 V , $GND = 0.0\text{ V}$ (unless otherwise noted)⁽¹⁾⁽²⁾

PARAMETER	TEST CONDITIONS	$T_A = -40^\circ\text{C}$			$T_A = 25^\circ\text{C}$			$T_A = 85^\circ\text{C}$			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
f_{MAX}	Maximum switching frequency	At $V_{ol} < 0.5\text{ V}$ (See Figure 4)			200			200			MHz
$t_{\text{PLH}}/t_{\text{PHL}}$	Propagation delay times	2	4.5		2	4.5		2	4.5		ns
t_{JITTER}	Random clock jitter (RMS)		5	20		5	20		5	20	ps
V_{PP}	Input swing	See ⁽³⁾			200	1000		200	1000		mV
t_r/t_f	Output rise/fall times	Q (10%–90%)			750			780			ps

- (1) The device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfm. Electrical parameters are assured only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.
- (2) $R_L = 500\ \Omega$ to GND and $C_L = 20\text{ pF}$ to GND . See Figure 1.
- (3) $V_{\text{PP}(\text{min})}$ is minimum input swing for which ac parameters are assured.

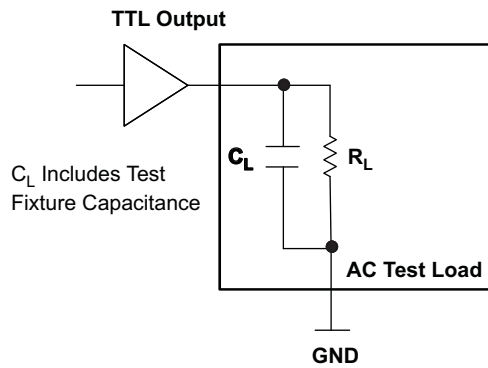


Figure 1. TTL Output AC Test Loading Condition

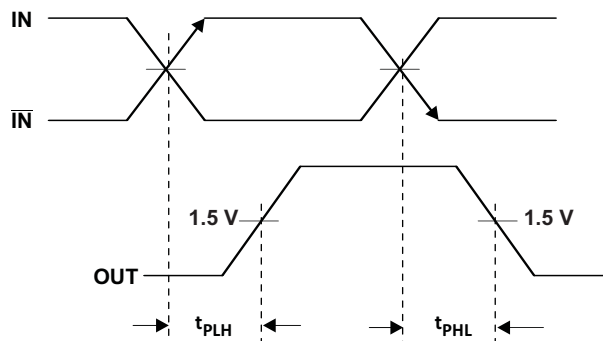


Figure 2. Output Propagation Delay

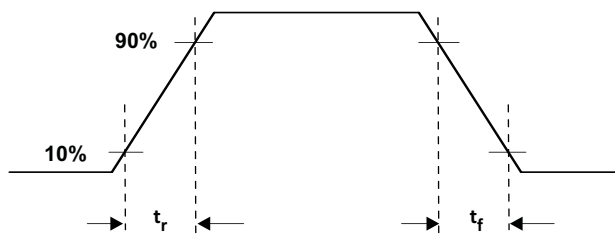
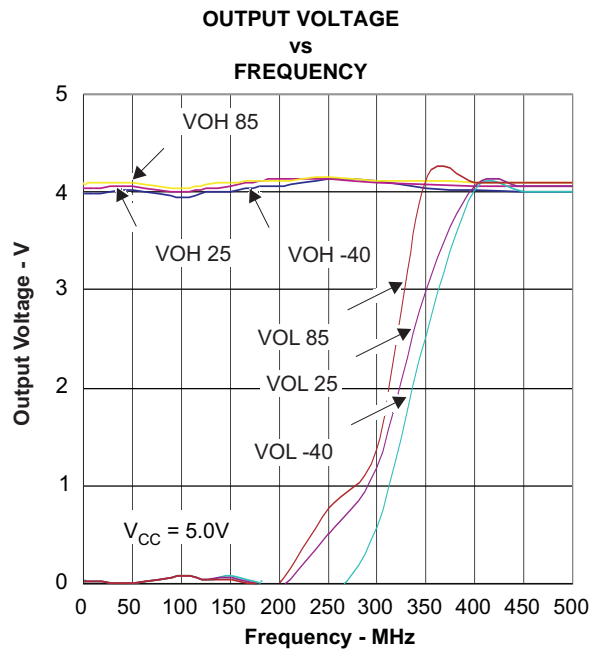


Figure 3. Output Rise and Fall Times



PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
SN65ELT21D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ELT21	Samples
SN65ELT21DGK	ACTIVE	VSSOP	DGK	8	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIII	Samples
SN65ELT21DGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	SIII	Samples
SN65ELT21DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ELT21	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

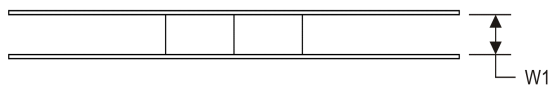
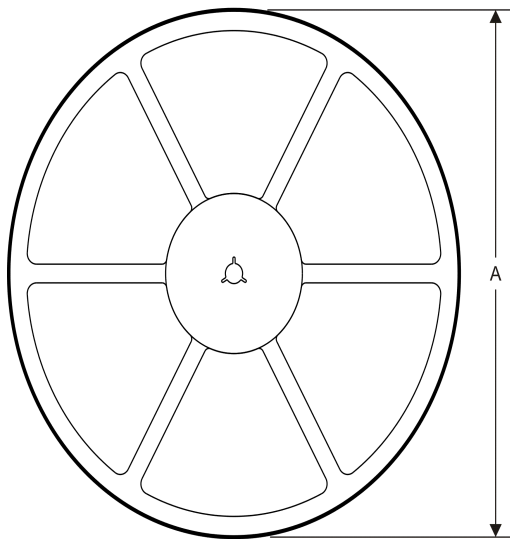
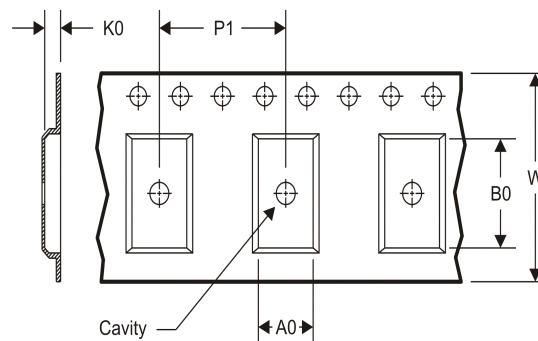
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

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TAPE AND REEL INFORMATION
REEL DIMENSIONS

TAPE DIMENSIONS


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

TAPE AND REEL INFORMATION

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65ELT21DGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
SN65ELT21DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65ELT21DGKR	VSSOP	DGK	8	2500	367.0	367.0	35.0
SN65ELT21DR	SOIC	D	8	2500	367.0	367.0	35.0

DGK (S-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 - E. Falls within JEDEC MO-187 variation AA, except interlead flash.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
 - E. Reference JEDEC MS-012 variation AA.

D (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

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